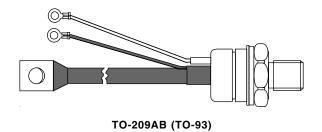


## Vishay High Power Products

## **Phase Control Thyristors** (Stud Version), 200 A



### **FEATURES**

- · Center amplifying gate
- International standard case TO-209AB (TO-93)



· Hermetic metal case with ceramic insulator (Also available with glass-metal seal up to 1200 V)

- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- · Lead (Pb)-free
- Designed and qualified for industrial level

PRODUCT SUMMARY				
I <sub>T(AV)</sub>	200 A			

#### **TYPICAL APPLICATIONS**

- · DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		200	А	
I <sub>T(AV)</sub>	T <sub>C</sub>	85	°C	
I <sub>T(RMS)</sub>		314	Α	
	50 Hz	5000	A	
I <sub>TSM</sub>	60 Hz	5230	A	
l²t	50 Hz	125	kA <sup>2</sup> s	
1-1	60 Hz	114	KA-S	
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 2000	V	
tq	Typical	100	μs	
T <sub>J</sub>		- 40 to 125	°C	

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA			
	04	400	500				
	08	800	900				
ST180S	12	1200	1300	30			
	16	1600	1700				
	20	2000	2100				

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## ST180SPbF Series

# Vishay High Power Products Phase Control Thyristors (Stud Version), 200 A



ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL		TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	180° condu	ction half sine v	vave	200	Α
at case temperature	'I(AV)	180° conduction, half sine wave		85	°C	
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 76 °C	case temperati	ure	314	
		t = 10 ms	No voltage		5000	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		5230	A kA <sup>2</sup> s
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		4200	
		t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	4400	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 10 ms	No voltage		125	
		t = 8.3 ms	reapplied		114	
		t = 10 ms	100 % V <sub>RRM</sub>		88	
		t = 8.3 ms	reapplied		81	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10	ms, no voltage	reapplied	1250	kA²√s
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$ , $T_J = T_J$ maximum	1.08	V
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(A)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		1.14	V
Low level value of on-state slope resistance	r <sub>t1</sub>	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$		1.18	<b>m</b> 0	
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		1.14	mΩ	
Maximum on-state voltage	$V_{TM}$	$I_{pk}$ = 570 A, $T_J$ = 125 °C, $t_p$ = 10 ms sine pulse		1.75	V	
Maximum holding current	I <sub>H</sub>			600	mA	
Maximum (typical) latching current	ΙL	T <sub>J</sub> = T <sub>J</sub> maximum, anode supply 12 V resistive load 1000 (300			1000 (300)	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ $V_{DRM}$	1000	A/µs
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1$ A/ $\mu$ s $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	1.0	
Typical turn-off time	t <sub>q</sub>	$I_{TM} = 300 \text{ A, } T_J = T_J \text{ maximum, } dI/dt = 20 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, } dV/dt = 20 \text{ V/}\mu\text{s, } \text{gate } 0 \text{ V } 100 \Omega, t_p = 500 \mu\text{s}$	100	μs

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$	500	V/µs	
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	30	mA	

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# Phase Control Thyristors (Stud Version), 200 A

# Vishay High Power Products

TRIGGERING						
DADAMETER	CVMDOL	_	TEGT COURTIONS		VALUES	
PARAMETER	SYMBOL	'	EST CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum,	, t <sub>p</sub> ≤ 5 ms	1	0	w
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	, f = 50 Hz, d% = 50	2	.0	] vv
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	, t <sub>p</sub> ≤ 5 ms	3	.0	Α
Maximum peak positive gate voltage	+ V <sub>GM</sub>	$T_{.l} = T_{.l}$ maximum, $t_n \le 5$ ms		0	V	
Maximum peak negative gate voltage	- V <sub>GM</sub>			5.0		V
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest value which will trigger all units	180	-	mA
DC gate current required to trigger		T <sub>J</sub> = 25 °C		90	150	
		T <sub>J</sub> = 125 °C		40	-	
		T <sub>J</sub> = - 40 °C		2.9	-	
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T <sub>J</sub> = 125 °C		1.2	-	-
DC gate current not to trigger	I <sub>GD</sub>	T - T movimum	Maximum gate current/voltage not to trigger is the maximum	1	0	mA
DC gate voltage not to trigger	V <sub>GD</sub>	$T_J = T_J \text{ maximum}$	value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	0.	25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	TJ		- 40 to 125	°C	
Maximum storage temperature range	T <sub>Stg</sub>		- 40 to 150		
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation 0.105		K/W	
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>	Mounting surface, smooth, flat and greased	0.04	- r./vv	
Mounting torque, ± 10 %		Non-lubricated threads	31 (275)	N·m	
Wounting torque, ± 10 /8		Lubricated threads	24.5 (210)	(lbf · in)	
Approximate weight			280	g	
Case style		See dimensions - link at the end of datasheeet TO-209AB (TO-93)		O-93)	

△R <sub>thJC</sub> CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.015	0.012				
120°	0.019	0.020				
90°	0.025	0.027	$T_J = T_J$ maximum	K/W		
60°	0.036	0.037				
30°	0.060	0.060				

#### Note

 $\bullet \ \ \, \text{The table above shows the increment of thermal resistance } \, R_{\text{thJC}} \, \text{when devices operate at different conduction angles than DC} \,$ 

# Vishay High Power Products Phase Control Thyristors (Stud Version), 200 A



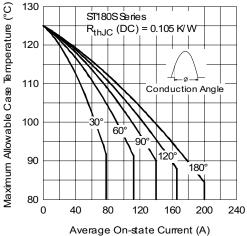


Fig. 1 - Current Ratings Characteristics

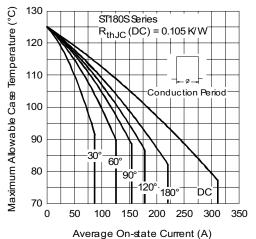


Fig. 2 - Current Ratings Characteristics

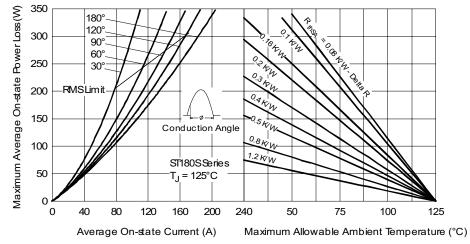


Fig. 3 - On-State Power Loss Characteristics

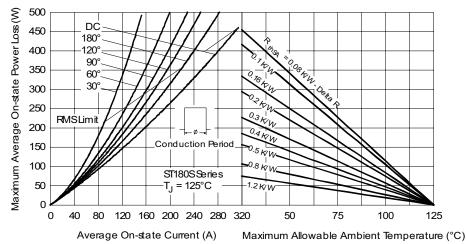


Fig. 4 - On-State Power Loss Characteristics



# Phase Control Thyristors (Stud Version), 200 A

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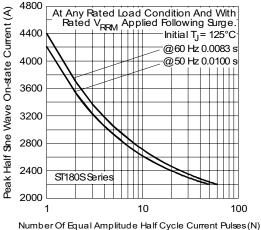


Fig. 5 - Maximum Non-Repetitive Surge Current

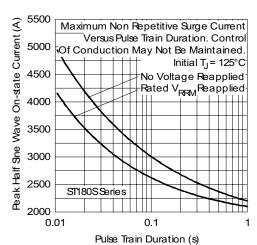


Fig. 6 - Maximum Non-Repetitive Surge Current

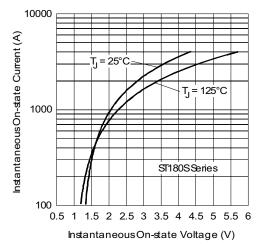


Fig. 7 - On-State Voltage Drop Characteristics

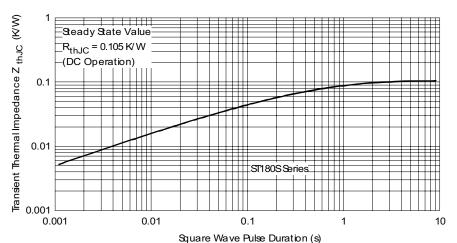
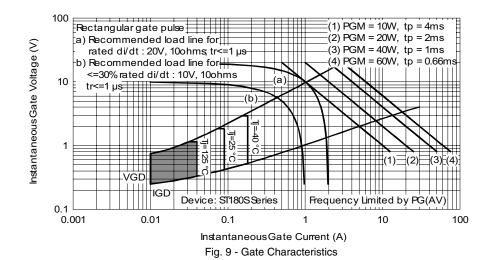


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

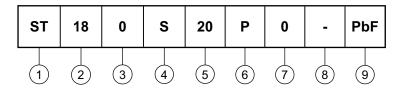
# Vishay High Power Products Phase Control Thyristors (Stud Version), 200 A





#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Thyristor
- 2 Essential part number
- 3 0 = Converter grade
- 4 S = Compression bonding stud
- 5 Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)
- P = Stud base 3/4"-16UNF2A threads
- 7 0 = Eyelet terminals (gate and auxiliary cathode leads)
  - 1 = Fast-on terminals (gate and auxiliary cathode leads)
- 8 V = Glass-metal seal (only up to 1200 V)

None = Ceramic housing (over 1200 V)

9 - Lead (Pb)-free

Note: For metric device M16 x 1.5 contact factory

LINKS TO RELATED DOCUMENTS		
Dimensions	http://www.vishay.com/doc?95082	

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